





## LOW V<sub>CE(SAT)</sub> NPN SURFACE MOUNT TRANSISTOR

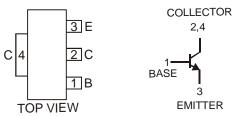
#### **Features**

- **Epitaxial Planar Die Construction**
- Low Collector-Emitter Saturation Resistance  $R_{\text{CE(SAT)}}$  =  $75\text{m}\Omega$  at 4A
- Complementary PNP Type Available (2DB1386)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

# **Mechanical Data**

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)





Schematic and Pin Configuration

# **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	20	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Peak Pulse Current	Ісм	10	A
Continuous Collector Current	Ic	5	A

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T <sub>A</sub> = 25°C	P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T <sub>A</sub> = 25°C	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

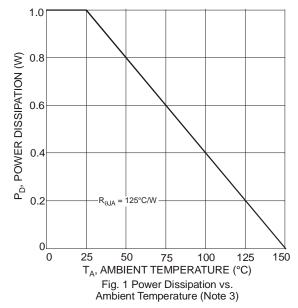
## Electrical Characteristics @TA = 25°C unless otherwise specified

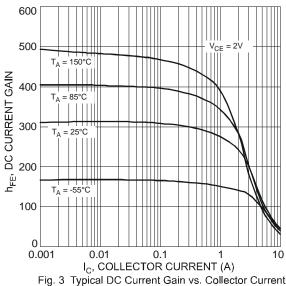
Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	50	_	_	V	$I_C = 50 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	20	_	_	V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6	_	_	V	$I_E = 50 \mu A, I_C = 0$
Collector Cut-Off Current	I <sub>CBO</sub>	_	_	0.5	μΑ	$V_{CB} = 40V, I_{E} = 0$
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	0.5	μΑ	$V_{EB} = 5V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		0.3	1.0	V	$I_C = 4A, I_B = 0.1A$
DC Current Gain	h <sub>FE</sub>	180	_	390	_	$I_C = 0.5A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f <sub>T</sub>	_	220	_	MHz	$V_{CE} = 6V$ , $I_E = -50$ mA f = 100MHz
Output Capacitance	C <sub>ob</sub>	_	14	_	pF	$V_{CB} = 20V, I_{E} = 0,$ f = 1MHz

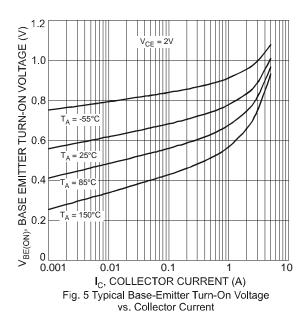
Notes: No purposefully added lead.

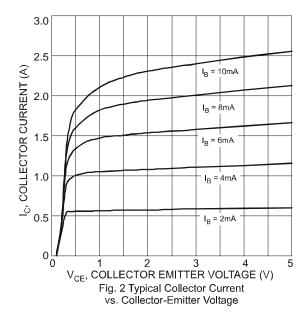
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.











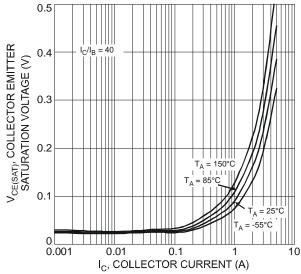


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

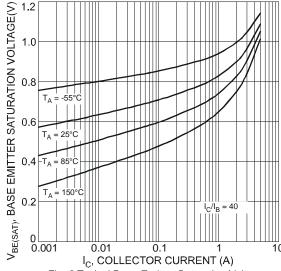
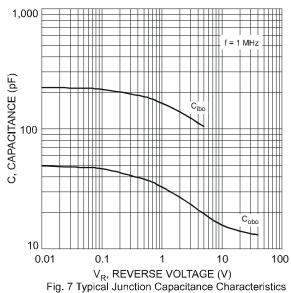
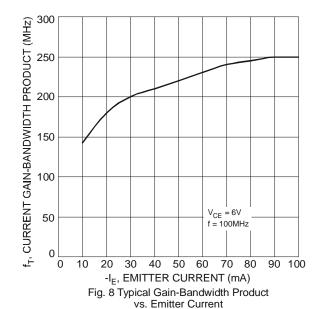


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current





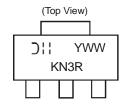


# Ordering Information (Note 5)

Device	Packaging	Shipping
2DD2098R-13	SOT89-3L	2500/Tape & Reel

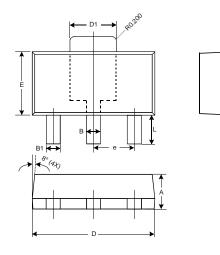
5. For packaging details, please see below or go to our website at http://www.diodes.com/ap02007.pdf.

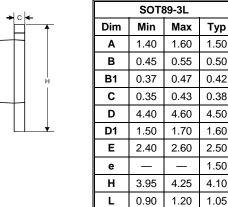
# **Marking Information**



KN3R = Product Type Marking Code Oll = Manufacturer's Marking Code YWW = Date Code Marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

# **Package Outline Dimensions**

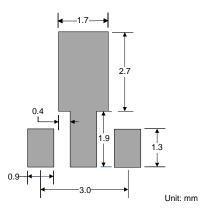




All Dimensions in mm



# **Suggested Pad Layout**



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